

30V N-Channel Enhancement Mode MOSFET

Voltage 30 V Current 6.8 A

Features

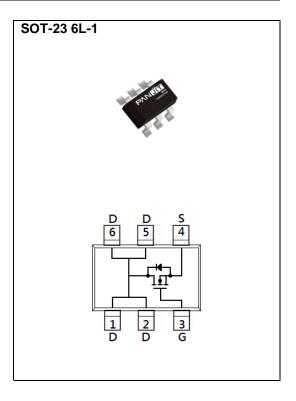
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_{D}@6.8A<29m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@4.3A<44m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc..
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: SOT-23 6L-1 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.014 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	30		
Gate-Source Voltage		V _G s	<u>+</u> 20	V	
Continuous Drain Current(Note 4)	T _A =25°C		6.8	A	
	T _A =70°C	l _D	5.3		
Pulsed Drain Current	T _A =25°C	I _{DM}	27.2		
Power Dissipation(Note 1)	T _a =25°C	P _D	2	W	
	Derate above 25°C		16	mW/°C	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Thermal Resistance					
- Junction to Ambient ^(Note 3)		R _θ JA	62.5	°C/W	



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA V _{DS} =V _{GS} , I _D =250uA	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$		1	1.5	2.1	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =6.8A	-	23	29	mΩ
		V _{GS} =4.5V, I _D =4.3A	-	34	44	
Zero Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	Q_g	V _{DS} =15V, I _D =6.8A, V _{GS} =10V ^(Note 1,2)	-	8.4	12	nC
Gate-Source Charge	Qgs		-	1.5	-	
Gate-Drain Charge	Q_{gd}		-	1.2	-	
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V,	-	368	550	pF
Output Capacitance	Coss		-	49	85	
Reverse Transfer Capacitance	Crss	I= I IVI IZ	-	40	70	
Switching						
Turn-On Delay Time	td _(on)	V_{DD} =15V, I_{D} =6.8A, V_{GS} =10V, R_{G} =6 $\Omega^{(Note~1,2)}$	-	4.2	-	
Turn-On Rise Time	tr		-	2.3	-	
Turn-Off Delay Time	td _(off)		-	13	-	ns
Turn-Off Fall Time	tf	KG=012(1000 1,2)	-	3.2	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	1-			_	2	А
Diode Forward Current	ls		_	-		
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.8	1.2	V

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.



TYPICAL CHARACTERISTIC CURVES

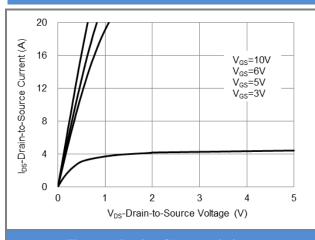


Fig.1 On-Region Characteristics

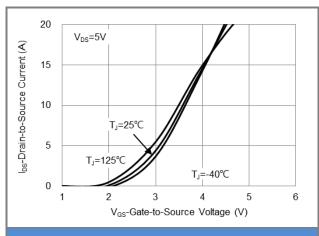


Fig.2 Transfer Characteristics

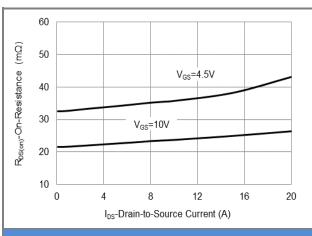


Fig.3 On-Resistance vs. Drain Current

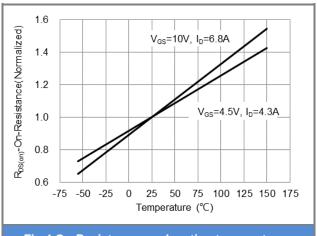
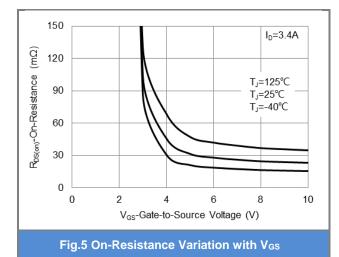


Fig.4 On-Resistance vs. Junction temperature



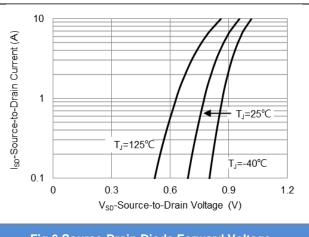


Fig.6 Source-Drain Diode Forward Voltage



TYPICAL CHARACTERISTIC CURVES

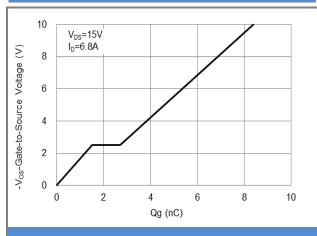


Fig.7 Gate-Charge Characteristics

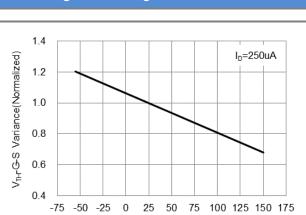


Fig.9 Threshold Voltage Variation with Temperature

Temperature (°C)

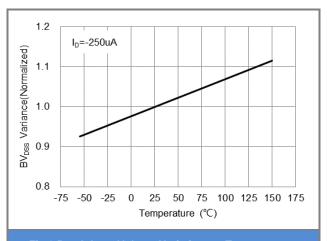


Fig.8 Breakdown Voltage Variation vs. Temperature

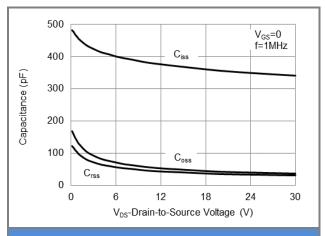


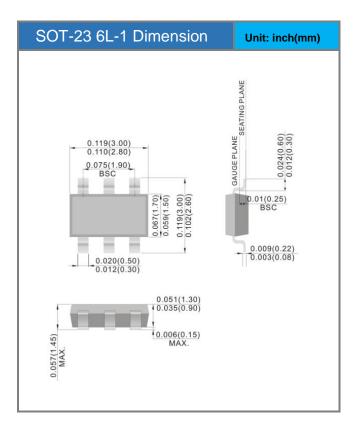
Fig.10 Capacitance vs. Drain-Source Voltage

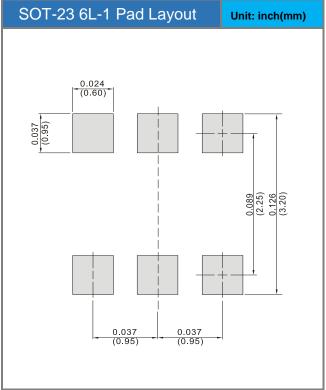


Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJS6404-AU	SOT-23 6L-1	3K pcs / 7" reel	S04

Packaging Information & Mounting Pad Layout







Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are
 responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no
 representation or warranty that such applications will be suitable for the specified use without further testing or
 modification.
- The products shown herein are not designed and authorized for equipments relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.